FAST HIGH VOLTAGE THYRISTOR SWITCHES

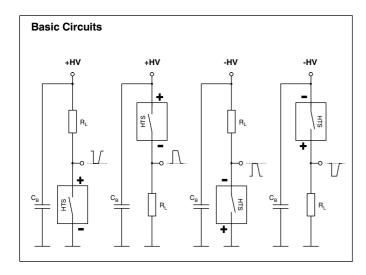
These solid-state switches are designed for high voltage high peak current switching applications such as shock wave generators, flash lamp drivers, crow bar circuits and surge generators. The switching modules contain a large number of reverse blocking thyristors (SCR) with a special chip architecture for high surge conditions. Several hundred of these SCR's, each with its own low-impedance gate drive, are connected in series and in parallel to ensure the extreme di/dt of up to 16 kA/ μ s. The safe and synchronous control of all SCR's is performed by a patented driver which provides also the high galvanic isolation necessary for high-side circuits and safety-relevant applications.

The switching modules described here are specially designed for civilian purposes and do not fall under 3A228c of the BIS Commerce Control List (Germany: 3A228c of BAFA Ausfuhrliste). Please note in this connection: SCR products marked with "SCR/DT" or option "DT-.." show turn-on delay times of at least $1\mu s$ and have a significant time jitter. Synchronization I/O's are not available for those products.

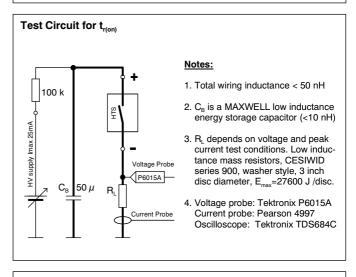
In contrast to conventional high voltage switches like spark gaps, electron tubes, gas discharge tubes and mechanical switches, thyristor switches of the series SCR and SCR/DT show very stable switching characteristics independent of temperature and age. The mean time between failures (MTBF) is by several orders of magnitude higher than that of the classical HV switches.

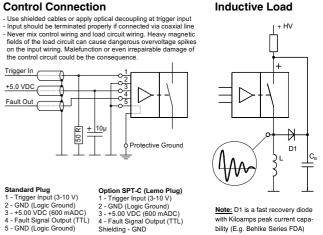
An interference-proof control circuit provides signal conditioning, auxiliary voltage monitoring, frequency limitation and temperature protection. In case of false operating conditions the switches are immediately inhibited and a fault signal is generated. Three LED's indicate the operating state. The switches are triggered by a positive going pulse of 3-10 Volts. The switching behaviour will not be influenced by the trigger rise time or the trigger amplitude. After being triggered the switches remain in on-state until the load current drops below the holding current (typical thyristor behaviour). The turn-off process requires insofar a current commutation, a current limitation or a current bypass. Capacitor discharge applications with charging currents less than the holding current do not require special turn-off measures. In all other cases the switches can be turned off by a slight current reversal, which is given in most pulsed power applications anyway. If the current reversal is higher than 10% and if the periodic duration of the current is shorter than 1 ms, a free-wheeling diode (e.g. Behlke FDA) must be used to avoid hard turn-off, which can damage the switching module under certain circumstances. Please compare also the application note below.

The plastic case is the cost-effective standard package in low frequency applications with low average power. For higher loads there are additional cooling options such as ceramic cooling surface, nonisolated cooling fins, grounded cooling flange or direct liquid cooling. With these options the Maximum Continuous Power Dissipation $P_{d(max)}$ can be increased from 50 to 30.000 Watts. For further design recommendations please refer to the general instructions.



HTS 240-1000-SCR/DT 24 kV / 10 kA HTS 220-1000-SCR/DT 22 kV / 10 kA HTS 220-1000-SCR with ceramic cooling surface (Opt. CCS) - F Patented +5V +HV TTL -HV Extremely High di/dt **High Surge Current Capability**





bility (E.a. Behlke Series FDA)

Specification	Symb.	Condition / Comment				220-1000-SCR/DT	240-1000-SCR/DT	Unit
Maximum Operating Voltage	$V_{O(max)}$	$I_{\text{off}} < 300 \ \mu\text{ADC}, \ T_{\text{case}} = 70^{\circ}\text{C}$			22000	24000	VDC	
Minimum Operating Voltage	$V_{\text{O}(\text{min})}$						0	VDC
Typical Breakdown Voltage	V_{br}	I _{off} > 3 mADC, T _{case} = 70°C				24200	26400	VDC
Maximum Off-State Current	I _{off}	0.8 x V _O , T _{case} = 25°C				300		μADC
Galvanic Isolation	Vı	HV side against control side, continuously			40000		VDC	
Maximum Turn-On Peak Current	I _{P(max)}	T_{case} / T_{fin} = 25°C, half t_p < 100 μ s, duty cycle <1%			10000			
		sine. Please consu	ult t _p < 500 μs	t_p < 500 μ s, duty cycle <1%		5000		
		factory for further	t _p < 1 ms	t _p < 1 ms, duty cycle <1%		3400		
		data.	t _p < 10 ms	, duty	cycle <1%	2	000	ADC
Max. Non-repetitive Peak Current	I _{P(nr)}	T _{case} / T _{fin} = 25°C	Half sine s	Half sine single pulse, tp<200 μ s		20000		
			Half sine s	Half sine single pulse, tp< 20µs		40	0000	ADC
Max. Continuous Load Current	IL	T _{case} / T _{fin} = 25°C Standard plastic case		ic case	0.74			
		With option CCS (air >4m/s)		2.22		ADC		
Typical Holding Current		T _{case} / T _{fin} = 25°C			50			
Typical Ficiality Guilloni		$T_{\text{case}} / T_{\text{fin}} = 70^{\circ} \text{C}$		35		mADC		
Typical On State Valtage	V			27				
Typical On-State Voltage	V_{sat}			0.01 x I _{P(max)} 0.1 x I _{P(max)} 1.0 x I _{P(max)}		45 120		VDC
		$t_p < 10\mu s$,						
		duty cycle <1%						
Typical Turn-On Rise Time	$t_{r(on)}$	Resistive load,		0.1 x V _{O(max)} , 0.1 x I _{P(max)}		500		
		10-80 %	0.8 x V _{O(m}				170	
			0.8 x V _{O(m}	,	` '		440	
			0.8 x V _{O(m}	$0.8 \times V_{O(max)}, I_P = 500 A$		300		ns
Typical Turn-On Delay Time	$t_{d(on)}$	Resistive load, 50-	50%		Standard "DT"		1	
		I _P = 500 A, 0.8 x \	$0.8 \times V_{O(max)}$		Option DT-10	10		μs
Total Turn-On Time	$t_{t(on)}$	$t_{d(on)}$ + $t_{r(on)}$, resistive load, 50-50% I_P = 500 A, 0.8 x $V_{O(max)}$		6	Standard "DT"		1.3	
	. ,				Option DT-10	1	0.3	μs
Typical Turn-Off Time	t _{off} , t _q	T _{case} / T _{fin} = 25°C, ii	nductive load	ctive load 0.1 x I _{P(max)}		35		
					1.0 x I _{P(max)}		90	
Critical Rate-of-Rise of Off-State Voltage	dv/dt	@ V _{O(max)} , exponential waveform			150		kV/μs	
Maximum On-Time	t _{on(max)}	Depends on holding current only.				unlimited		
Internal Driver Recovery Time	t _{rc}	Standard devices				1000		
		With option HFB			100		μs	
Typical Turn-On Jitter	t _{j(on)}			Standard "DT"		50		
	, ,				Option DT-10	Ę	500	ns
Max. Cont. Switching Frequency	f _(max)	Please note P _{d(max)} limitations				400		Hz
Maximum Burst Frequency	f _{b(max)}	With option HFB, I _{P(max)} <16 kA, please consult factory			1			
(Triggered)	, ,	With option HFB, I _{P(max)} <3 kA, please consult factory			10		kHz	
Maximum Continuous Power	$P_{d(max)}$	T _{case} = 25°C Standard plastic case				20		
Dissipation	, ,	With option CCS (air stream		r stream >4m/s)	60		Watts	
Linear Derating		Above 25°C T _{case} Standard plastic case With option CCS (air stream >4m/s)		dard plastic case		C).44	
5					.33	W/K		
Temperature Range	To				085	°C		
Coupling Capacitance	C _C	HV side against control side				270	pF	
Auxiliary Supply Voltage	V _{aux}	Stabilized to ± 5% (4.755.25 VDC)			5.00		VDC	
Auxiliary Supply Current		@ f _(max)				300	mADC	
	I _{aux}	Switching behaviour is not influenced by trigger			3-10		VDC	
Trigger Voltage Range	V_{tr}	quality			3	D-10	VDC	
Fault Signal Output		Short circuit proof, source/sink current max. 10mADC (TTL compatible) Ready = High Fault = Low				4.0		
rauli Signai Output						·4.0	VDC	
Ourseless signation to a 1/Outset					<0.8		VDC	
Synchronization Input/Output		Short circuit proof, output pulse 4 VDC / 1ms				-		-
Operating Mode Indication		By LED's: Green=Ready, Yellow=Trigger, Red=Fault				-		-
High Voltage Connection		Low inductance terminals for printed circuit boards				-		-
Dimensions		Standard plastic case			252 x 150 x 40		_	
		With option CCS			160 x 150 x 30		mm ³	
Weight		Standard plastic case			1900			
		With option CCS				1500		g

ORDERING INFORMATION

HTS 220-1000-SCR/DTThyristor switch, 22 kVDC, 10 kA (pk)Option UL94-V0FHTS 240-1000-SCR/DTThyristor switch, 24 kVDC, 10 kA (pk)Option DT-10DOption CCSCeramic Cooling SurfaceFor further options please